

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





NPN SILICON PLANAR TRANSISTORS



BC107/A/B/C BC108/A/B/C BC109/A/B/C

TO-18 Metal Can Package

Low Noise General Purpose Audio Amplifiers

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BC107	BC108	BC109	UNIT
Collector Emitter Voltage	V_{CEO}	45	25	25	V
Collector Base Voltage	V_{CBO}	50	30	30	V
Emitter Base Voltage	V_{EBO}	6.0	5.0	5.0	V
Collector Current Continuous	Ic	200			
Power Dissipation at T _a =25°C	P_D	300			
Derate above 25ºC		1.72			
Power Dissipation at T _c =25°C	P_{D}	750			
Derate above 25°C		4.29 r			
Operating And Storage Junction Temperature Range	T_j , T_{stg}	- 65 to +200			

THERMAL CHARACTERISTICS

Junction to Ambient in free air	R _{th (j-a)}	583	ºC/W
Junction to Case	R _{th (j-c)}	233	ºC/W

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	BC107	BC108	BC109	UNIT
Collector Emitter Voltage	V_{CEO}	$I_C=2mA$, $I_{B=}0$	>45	>45 >25 >25		
Emitter Base Voltage	ter Base Voltage V_{EBO} $I_{E}=10\mu A, I_{C}=0$ >6			>5	>5	V
Collector Cut Off Current	I _{CBO}	$V_{CB} = 45V, I_{E} = 0$ <15				nA
		$V_{CB}=25V$, $I_{E}=0$		<15	<15	nA
		$V_{CB}=45V$, $I_{E}=0$, $T_{a}=125^{\circ}C$	<4			μΑ
		$V_{CB}=25V, I_{E}=0, T_{a}=125^{\circ}C$				
DC Current Gain	h _{FE}	$I_C=10\mu A, V_{CE}=5V$				
		B Group	>40			
		C Group	>100			
		I _C =2mA, V _{CE} =5V				
		BC107		110-450		
		BC108	110-800			
		BC109	200-800			
		A Group	110-220			
		B Group	200-450			
		C Group		420-800		

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ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Emitter Saturation Voltage	V _{CE (sat)}	$I_C=10$ mA, $I_B=0.5$ mA		·	0.25	٧
		I _C =100mA, I _B =5mA			0.60	V
Base Emitter Saturation Voltage	V _{BE (sat)}	I _C =10mA, I _B =0.5mA			0.83	V
		I _C =100mA, I _B =5mA			1.05	V
Base Emitter On Voltage	V _{BE (on)}	$I_C=2mA, V_{CE}=5V$	0.55		0.70	V
		I _C =10mA, V _{CE} =5V			0.77	V
Callacter Knee Voltage	V	$I_C=10$ mA, $I_B=$ the value for which			0.60	V
Collector Knee Voltage	V _{CE (K)}	$I_C=11$ mA at $V_{CE}=1$ V				
Transition frequency	f _T	I _C =10mA, V _{CE} =5V, f=100MHz	150			MHz
Output Capacitance	C_{obo}	$V_{CB}=10V$, $I_{E}=0$, $f=1MHz$			4.5	рF
Noise Figure	NF	$I_C=0.2$ mA, $V_{CE}=5$ V, Rg=2K Ω ,				
		f=30Hz to 15KHz BC109			4.0	dB
		f=1KHz, ΔF=200Hz, BC109			4.0	dB
		BC107/108			10	dB

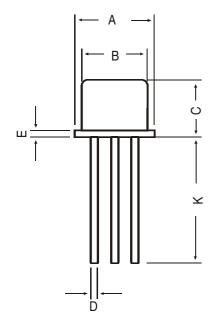
SMALL SIGNAL CHARACTERISTICS

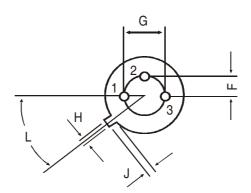
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Small Signal Current Gain	h _{fe}	$I_C=2mA$, $V_{CE}=5V$, $f=1KHz$				
		BC107	125		500	
		BC108	125		900	
		BC109	240		900	
		A Group	125		260	
		B Group	240		500	
		C Group	450		900	
Input Impedance	h _{ie}	$I_C=2mA$, $V_{CE}=5V$, $f=1KHz$				
		A Group	1.6		4.5	ΚΩ
		B Group	3.2		8.5	ΚΩ
		C Group	6.0		15	ΚΩ
Output Admittance	h _{oe}	$I_C=2mA$, $V_{CE}=5V$, $f=1KHz$				
		A Group			30	μmhos
		B Group			60	μmhos
		C Group			110	μmhos

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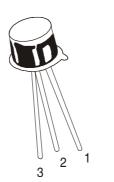
TO-18 Metal Can Package

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	DIM	MIN	MAX						
	Α	5.24	5.84						
	В	4.52	4.97						
	С	4.31	5.33						
	D	0.40	0.53						
	Ε	1	0.76						
	F	1	1.27						
	G	1	2.97						
	Н	0.91	1.17						
	J	0.71	1.21						
	K	12.70	_						
	L	45 DEG							



PIN CONFIGURATION

- 1. EMITTER
- 2. BASE 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-18	1K/polybag	350 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	34 kgs

Notes

BC107/A/B/C BC108/A/B/C BC109/A/B/C

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Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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